

GPP20A - GPP20M

AXIAL LEADED SILICON RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V CURRENT: 2.0 A

Features

Diffused Junction

Low Forward Voltage Drop

High Current Capability

High Reliability

High Surge Current Capability

Mechanical Data

Case: D O - 1 5

Terminals: Plated Leads Solderable per

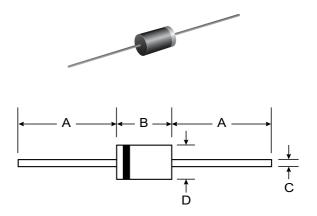
MIL-STD-202, Method 208

Polarity: Cathode Band

• Weight: 0.40 grams (approx.)

Mounting Position: AnyMarking: Type Number





DO-15						
Dim	Min	Max				
Α	25.40	_				
В	5.50	7.62				
С	0.686	0.889				
D	2.60	3.60				
All Dimensions in mm						

Maximum Ratings and Electrical Characteristics T_A = 25°C unless otherwise specified

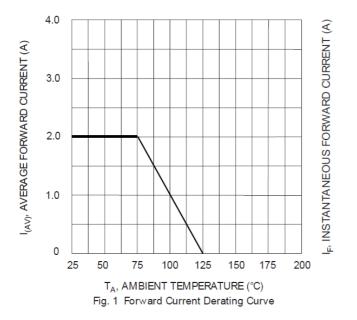
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	GPP20A	GPP20B	GPP20D	GPP20G	GPP20J	GPP20K	GPP20M	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	٧
Average Rectified Output Current (Note 1)	lo	2.0						Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	70					А		
Forward Voltage @I _F = 2.0A	VFM	1.0						V	
	lгм	5.0 50						μΑ	
Typical Junction Capacitance (Note 2)	Cj	20					pF		
Typical Thermal Resistance Junction to Ambient (Note 1)	R heta JA	40					K/W		
Operating Temperature Range	Tj	-65 to +125					°C		
Storage Temperature Range	Tstg	-65 to +150					°C		

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.





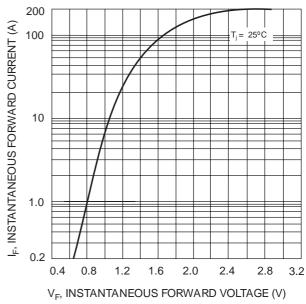
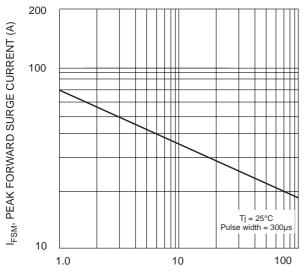
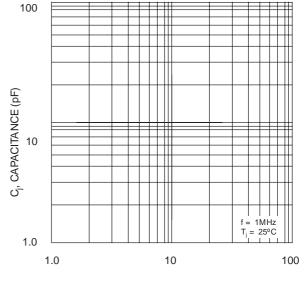


Fig. 2 Typical Forward Characteristics



NUMBER OF CYCLES AT 60Hz Fig. 3 Maximum Non-Repetitive Surge Current



V_R, REVERSE VOLTAGE (V) Fig. 4 Typical Junction Capacitance